Non-equilibrium steady state of "sparse" systems

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 $\mathcal{H}_{\text{total}} = \text{diag}\{E_n\} - f(t)V_{nm} + F(t)W_{nm} + Bath$

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- [2] Hurowitz, Rahav, Cohen (EPL 2012)
- [3] Stotland, Pecora, Cohen (EPL 2010, PRE 2011)
- [4] Stotland, Cohen, Davidson (EPL 2009)

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Current versus driving

Driving \rightsquigarrow Stochastic Motive Force \rightsquigarrow Current Regimes: LRT regime, Sinai regime, Saturation regime



$$I \sim \frac{1}{N} \overline{w} \exp\left[-\frac{\mathcal{E}_{\cap}}{2}\right] 2 \sinh\left(\frac{\mathcal{E}_{\odot}}{2}\right)$$

Master equation description of dynamics

$$\mathcal{H}_{\text{total}} = \text{diag}\{E_n\} - \frac{f(t)V_{nm} + F(t)W_{nm} + Bath}{Bath}$$

Quantum master equation for the reduced probability matrix:

$$\frac{d\rho}{dt} = -i[\mathcal{H}_0, \rho] - \frac{\varepsilon^2}{2} [V, [V, \rho]] + \mathcal{W}^\beta \rho$$

Corresponding stochastic rate equation:

$$\frac{dp_n}{dt} = \sum_m w_{nm} p_m - w_{mn} p_n$$

$$w_{nm} = w_{nm}^{\varepsilon} + w_{nm}^{\beta}$$
$$w_{nm}^{\varepsilon} = w_{mn}^{\varepsilon} \propto \varepsilon^{2}$$
$$\frac{w_{nm}^{\beta}}{w_{mn}^{\beta}} = \exp\left[-\frac{E_{n} - E_{m}}{T_{B}}\right]$$

Steady state equation:

$$\dot{
ho} = \mathcal{W}
ho = 0$$

The Stochastic Motive Force





The "potential" variation along a segment

$$\mathcal{E}(x_1 \rightsquigarrow x_2) = \sum_{x=x_1}^{x_2} \mathcal{E}(x) = \int_{x_1}^{x_2} \mathcal{E}(x) dx$$
$$\mathcal{E}_{\cap} \equiv \max \left\{ |\mathcal{E}(x_1 \rightsquigarrow x_2)| \right\}$$
$$\mathcal{E}_{\circlearrowleft} \equiv \oint \mathcal{E}(x) dx \qquad \text{if no driving} = 0$$

The emergence of Sinai regime

Sinai [1982]: Transport in a chain with random transition rates. Assume transition rates are uncorrelated.

- \rightsquigarrow exponential build up of a potential barrier $\mathcal{E}_{\cap} \propto \sqrt{N}$
- \rightsquigarrow exponentially small current.

But... we have telescopic correlations: $\mathcal{E}_{n,n+1} \sim \Delta_n \equiv (E_n - E_{n+1})$

$$\mathcal{E}_{\circlearrowleft} \approx -\sum_{n} \left[\frac{1}{1+g_{n}\epsilon^{2}} \right] \frac{\Delta_{n}}{T_{B}} \sim \frac{1}{T_{B}} \begin{cases} \epsilon^{2}, & \epsilon^{2} < 1/g_{\max} \\ 1/\epsilon^{2}, & \epsilon^{2} > 1/g_{\min} \\ [\pm]\sqrt{N}\Delta, & \text{otherwise} \end{cases}$$

Build up may occur if g_n are from a **log-wide** distribution.

$$I \sim \frac{1}{N} \overline{w} \exp\left[-\frac{\mathcal{E}_{\cap}}{2}\right] 2 \sinh\left(\frac{\mathcal{E}_{\circ}}{2}\right)$$

"Sparsity" of weakly chaotic systems

$$\mathcal{H}_{\text{total}} = \text{diag}\{E_n\} - f(t)V_{nm}$$



not a Gaussian matrix...



[log-wide distribution]



 $[median \ll mean]$

 $\operatorname{mean}[|V_{nm}|^2] \approx (2\pi\varrho)^{-1} \tilde{C}_{cl}(E_n - E_m)$

Motivation for this line of study

B The Kubo–Greenwood conductivity and the Edwards–Thouless relationships

Writing (but being aware of the subtleties) the matrix elements of x in terms of those of v, noting, for example, that for positive ω , $\omega = \omega_{ng}$, one expresses the low-frequency real conductivity σ_{xx} , from eq. A.7 inserting the volume of the system, Vol, as

$$\operatorname{Re}\sigma(\omega) = \frac{\pi e^2}{Vol\hbar\omega} \sum_{n} |v_{gn}|^2 \delta(\omega - \omega_{ng}), \qquad (B.1)$$

where the cartesian index x has been dropped for the diagonal conductivity, $\sigma_{xx} \equiv \sigma$. For noninteracting quasiparticles the excited states are particle-hole excitations where the hole can be created anywhere between ϵ_F and $\epsilon_F - \hbar \omega$. Replacing the $|v_{gn}|^2$ in this small range by an average value $\overline{v^2}$, one obtains, since the excitations are electron-hole ones

$$\sigma \equiv \operatorname{Re} \sigma(\omega \to 0) = \frac{\pi e^2 \hbar}{Vol} \overline{v^2} [N(0)]^2, \qquad (B.2)$$

where N(0) is the single-particle density of states per unit energy N(0) = n(0). Vol. This is called the Kubo-Greenwood formula. Note that this is valid for a large enough system having effectively a continuous spectrum. How to handle the discrete spectrum in mesoscopics is discussed in chapter 5.

usual expression for σ from eq. 5.1, one straightforwardly obtains the low-temperature d.c. conductivity by replacing the sums by integrals and assuming that $|\langle l|\hat{v}|k\rangle|^2$ has some typical value denoted by $|\langle v \rangle|^2$ near ϵ_F (see appendix B),

$$\sigma_{KG} = \pi e^2 Vol\hbar |\langle v \rangle|^2 [n(0)]^2.$$
(5.3)

Here n(0) is the density of states per unit volume, at ϵ_F . This is the Kubo–Greenwood conductivity (Kubo 1957, Greenwood 1958).

Appendix + Chapter5 from the book of Joe Imry

Question:

How to go beyond linear response?

- Average value?
- Typical value?

Answer:

"Resistor network average"

$$G \; = \; \pi \varrho^2 \; \langle \langle |V_{nm}|^2 \rangle \rangle$$

Estimate:

"Effective range hopping"

Applications:

Heating of cold atoms due to vibrating walls [beyond the "wall formula" of Swiatecki] Mesoscopic conductance of EMF-driven rings [beyond the "Drude formula"] Low frequency absorption of metallic grains [beyond Gorkov-Eliashberg]

Rate of heating

$$\mathcal{H}_{\text{total}} = \{E_n\} - \frac{f(t)}{V_{nm}}\}$$

$$g_s \equiv \frac{\langle \langle |V_{nm}|^2 \rangle \rangle_s}{\langle \langle |V_{nm}|^2 \rangle \rangle_a}$$

- f(t) =low freq noisy driving
- \rightarrow diffusion in energy space: $D_{\text{SLRT}} = g_s D_{\text{LRT}}$
- \rightarrow energy absorption:
- \dot{E} = (particles/energy) × D



[The "Drude Formula"]

Some numerical results

Beyond the "Wall Formula"

[Dependence on deformation U]

Beyond the "Drude Formula"

[Dependence on disorder W]







RMT modeling, generalized VRH approx scheme

- finite bandwidth b
- log-normal distribution s

 $s = (\text{median}/\text{mean})^2$

$$g_s \approx \sqrt{s} \exp\left[2\sqrt{-\ln\sqrt{s}\ln(b)}\right]$$



The energy absorption rate: the LRT to SLRT crossover

 $\mathcal{H}_{\text{total}} = \text{diag}\{E_n\} - f(t)V_{nm} + F(t)W_{nm} + Bath$



The generalized Fluctuation-Dissipation phenomenology

$$\mathcal{H}_{\text{total}} = \text{diag}\{E_n\} - f(t)V_{nm} + F(t)W_{nm} + Bath$$

$$\dot{W}$$
 = rate of heating = $\frac{D(\varepsilon)}{T_{\text{system}}}$
 \dot{Q} = rate of cooling = $\frac{D_B}{T_B} - \frac{D_B}{T_{\text{system}}}$

Hence at the NESS:

$$T_{\text{system}} = \left(1 + \frac{D(\varepsilon)}{D_B}\right) T_B$$
$$\dot{Q} = \dot{W} = \frac{1/T_B}{D_B^{-1} + D(\varepsilon)^{-1}}$$

Experimental way to extract response:

$$D(\varepsilon) = \frac{\dot{Q}(\varepsilon)}{\dot{Q}(\infty) - \dot{Q}(\varepsilon)} D_B$$



 $D(\varepsilon)$ exhibits LRT to SLRT crossover SLRT requires resistor network calculation

$$D_{LRT} = \overline{w_n}$$
$$D_{SLRT} = \left[\overline{1/w_n}\right]^{-1}$$

Semi-linear response:

 $\begin{array}{lll} D[\lambda \boldsymbol{w}] &=& \lambda D[\boldsymbol{w}] \\ D[\boldsymbol{w}^a + \boldsymbol{w}^b] &>& D[\boldsymbol{w}^a] + D[\boldsymbol{w}^b] \end{array}$

Experimental implication: $D\left[\lambda \tilde{S}(\omega)\right] = \lambda D\left[\tilde{S}(\omega)\right]$ but...

Beyond the Fluctuation-Dissipation phenomenology: Topological term in EAR formula

$$\dot{\mathbf{Q}} = \sum_{n} \left[w_{\overleftarrow{n}}^{\beta} p_{n} - w_{\overrightarrow{n}}^{\beta} p_{n-1} \right] \Delta_{n}$$

$$\approx \left[\frac{D_{B}}{T_{B}} - \frac{D_{B}}{T^{(0)}} \right] + T_{B} \mathcal{E}_{\circlearrowleft} I$$

$$\approx \frac{D_{B}}{T_{B}} \left[\overline{(g_{n} \epsilon^{2}) - (g_{n} \epsilon^{2})^{2}} + \operatorname{Var}(g) \epsilon^{4} \right]$$



The EAR is correlated with the current.

Why "sparsity" is interesting

- The energy absorption rate (EAR) requires a resistor network calculation.
- Semi-linear response characteristics, beyond LRT.
- Sparsity implies a novel NESS that has glassy nature.
- Novel quantum saturation effect.
- Current versus driving: emergence of a Sinai regime.
- Applications:

Heating rate of cold atom in billiards with vibrating walls [beyond Swiatecki] Absorption of low frequency irradiation by metallic grains [beyond Gorkov-Eliashberg] Conductance of mesoscopic EMF-driven ballistic rings [beyond Drude]







Conclusions

- (*) Wigner (~ 1955): "The perturbation is represented by a random matrix whose elements are taken from a Gaussian distribution." Not always...
- 1. "weak quantum chaos" \implies log-wide distribution, "sparsity" and "texture"
- 2. The heating \sim a percolation process.
- 3. Resistors network calculation to get the response coefficient.
- 4. RMT modeling \rightarrow generalization of the VRH estimate.
- 5. Experimental fingerprint: semi-linear response characteristics.
- 6. SLRT applies if the driving is stronger than the background relaxation.
- 7. The stochastic NESS has glassy characteristics (wide distribution of microscopic temperatures).
- 8. Definition of effective NESS temperature, and extension of the F-D phenomenology.
- 9. For very strong driving quantum saturation of the NESS temperature $(T \to T_{\infty})$.
- 10. Topological aspects: The emergence of the Sinai regime.
- 11. Topological term in the formula for the heating rate.
- 12. Applications: beyond the "Drude formula" and beyond the "Wall formula".

Perspective and references

The classical LRT approach: Ott, Brown, Grebogi, Wilkinson, Jarzynski, Robbins, Berry, Cohen The Wall formula (I): Blocki, Boneh, Nix, Randrup, Robel, Sierk, Swiatecki, Koonin The Wall formula (II): Barnett, Cohen, Heller [1] - regarding g_c Semi Linear response theory: Cohen, Kottos, Schanz... [2-6] Billiards with vibrating walls: Stotland, Cohen, Davidson, Pecora [7,8] - regarding g_s Sparsity: Austin, Wilkinson, Prosen, Robnik, Alhassid, Levine, Fyodorov, Chubykalo, Izrailev, Casati

Non Equilibrium: Lebowitz, Spohn, Gaspard, Seifert, Schnakenberg, [...] Sinai Physics: Sinai, Derrida, Pomeau, Burlatsky, Oshanin, Mogutov, Moreau, [...] Acknowledgment: Bernard Derrida

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